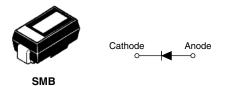


### Vishay High Power Products

## Schottky Rectifier, 1 A



PRODUCT SUMMARY				
I <sub>F(AV)</sub>	1.0 A			
V <sub>R</sub>	100 V			

### FEATURES

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

### DESCRIPTION

The 10BQ100PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I <sub>F(AV)</sub>	Rectangular waveform	1.0	A	
V <sub>RRM</sub>		100	V	
I <sub>FSM</sub>	$t_p = 5 \ \mu s \ sine$	780	A	
V <sub>F</sub>	1.0 Apk, T <sub>J</sub> = 125 °C	0.62	V	
TJ	Range	- 55 to 175	°C	

VOLTAGE RATINGS				
PARAMETER SYMBOL		10BQ100PbF	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	100	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>L</sub> = 152 °C, rectangular waveform		1.0	А
Maximum peak one cycle non-repetitive surge current		5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	780	A
	IFSM	10 ms sine or 6 ms rect. pulse		38	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.5 A, L = 8 mH		1.0	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 0.5		А	

## 10BQ100PbF

# Vishay High Power Products Schottky Rectifier, 1 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V (1)	1 A	T <sub>J</sub> = 25 °C	0.78	V
		2 A		0.89	
See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	1 A	- T <sub>J</sub> = 125 °C	0.62	
		2 A		0.72	
Maximum reverse leakage current See fig. 2	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5	mA	
	'RM \''	T <sub>J</sub> = 125 °C		1	ША
Typical junction capacitance	CT	$V_{R}$ = 5 $V_{DC}$ , (test signal range 100 kHz to 1 MHz) 25 °C		42	pF
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of charge	dV/dt	Rated V <sub>R</sub> 10 000		V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		- 55 to 175	°C	
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>	DC operation	36	°C AN	
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>		80	°C/W	
Approximate weight			0.10	g	
		0.003	oz.		
Marking device		Case style SMB (similar DO-214AA)	V	IJ	

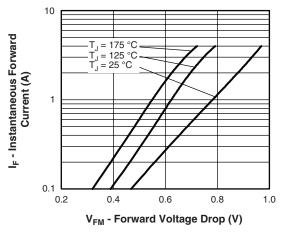
#### Notes

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB



Schottky Rectifier, 1 A Vishay High Power Products



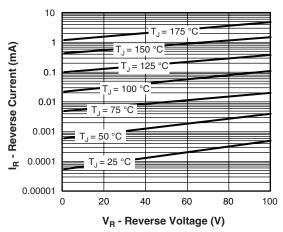


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

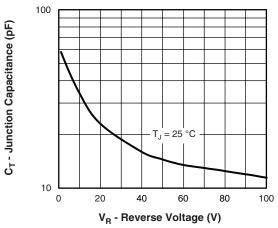


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

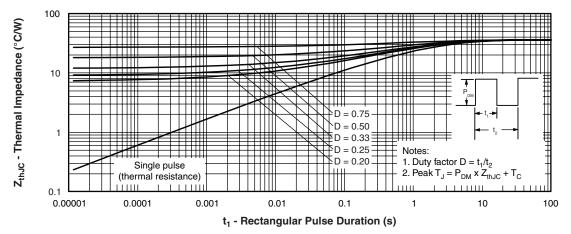


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

## 10BQ100PbF

### Vishay High Power Products Schottky Rectifier, 1 A

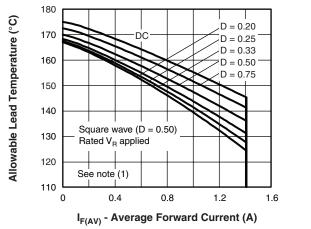
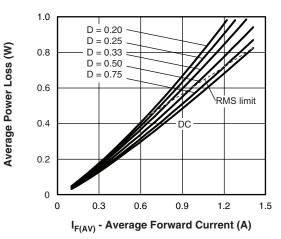
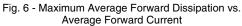
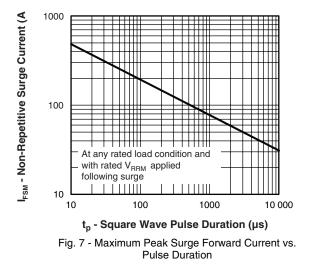


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature







#### Note

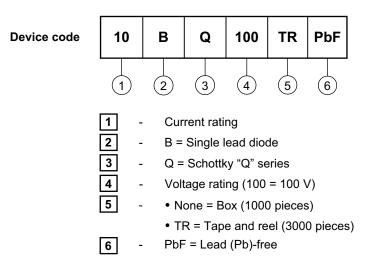
- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC};$   $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$  (see fig. 6);  $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 D); I_R at V_{R1} = 80 \% rated V_R$





Schottky Rectifier, 1 A Vishay High Power Products

#### ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95017				
Part marking information	www.vishay.com/doc?95029			
Packaging information	www.vishay.com/doc?95034			
SPICE model	www.vishay.com/doc?95276			



Vishay

## Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.